ENERCY STORAGE · Apply a voltage to two parallel conducting plates and wait a while Rs Vs Ŧ · what dowe have ! - no current flowing - positive charge on top plate - negative charge on bottom plate ⇒ electric field across the gap. · Now remove/disconnect the source - nowhere for charge to flow - electric field remains - energy stored in suppotential of charges. . How to use this?

Interesting idea! Let's try to model it so that we can use it.

Idealized setup - infinite plate

- infinite plates - perfect conductors
 - perfect insulator
 - perfectly uniform dielectric

In that case,

charge stored or voltage applied



q=CV

 $C = \frac{\epsilon A}{d}$

E = permitivity A= area. d= separation

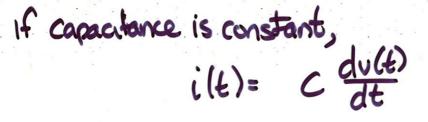
CIRCUIT MODEL

v(t) = c(t)

 $q(t) = (lt) \vee lt)$

what about current.

 $i(t) = \frac{dq(t)}{dt} = \frac{d}{dt} \left[(lt)v(t) \right]$



So what is v(t)? Assume v(t) | t= to is known. $v(t) = v(t_0) + \frac{1}{c} \int_{t_0}^{t} i(x) dx$

a choose to= - 00 Sometimes and assume v(-o)=0 $v(t) = t \int_{-\infty}^{t} i(x) dx$

The idea was to store energy How much did we store? $E(t) = \int_{0}^{t} p(x) dx.$ where p(t) is power:

p(t) = v(t) i(t) = C v(t) du(t)

 $E(t) = \int_{0}^{t} c v(x) \frac{d v(w)}{dx} dx$ $= C \int_{V(-\infty)}^{V(4)} v(x) dv(x)$ $= \frac{1}{2} C V(x)^{2} \int_{V(-\infty)}^{V(t)}$

If we assume $v(-\infty) = 0$, $E(t) = \frac{1}{2} C V(t)^{2}$

* Sometimes desirable + engineered * Sometimes undesirable + to be engineered away

PROPERTIES Velt) V(t) (C(t)

 $i(t) = C \frac{d V_c(t)}{dt}$

* what if V(E) is constant?

- current=0, no matter how big u(t) is
- ⇒ open circuit

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- have you seen this idea in use .
- * what if v(t) changes rapidly? - (ilt) / is large, even if v(t) is small -> short circuit

 $v(t) = \frac{1}{c} \int_{-\infty}^{t} i(x) dx$ what does this tell us about v(t)? Continuous